



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 - Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

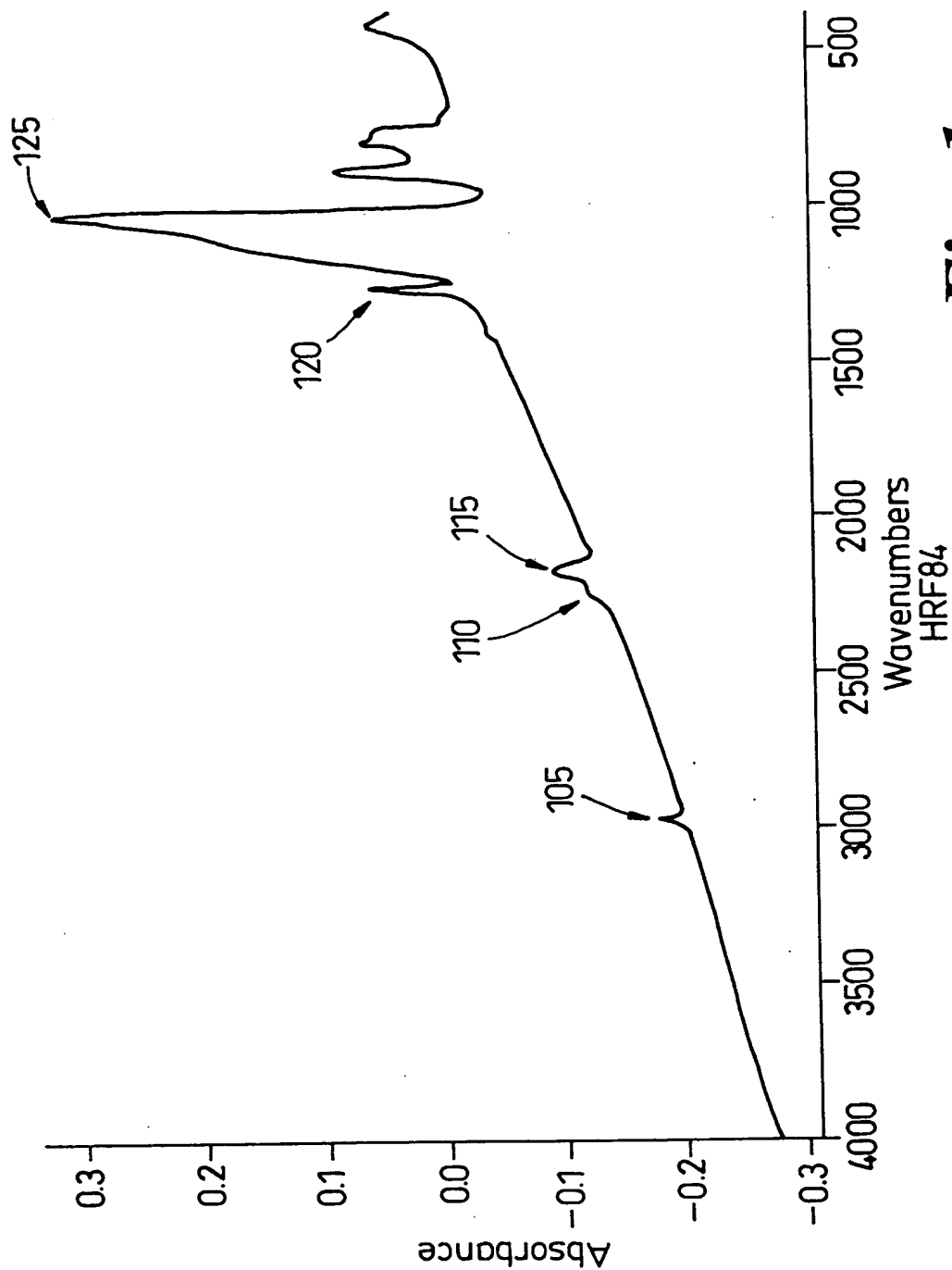


Fig. 1

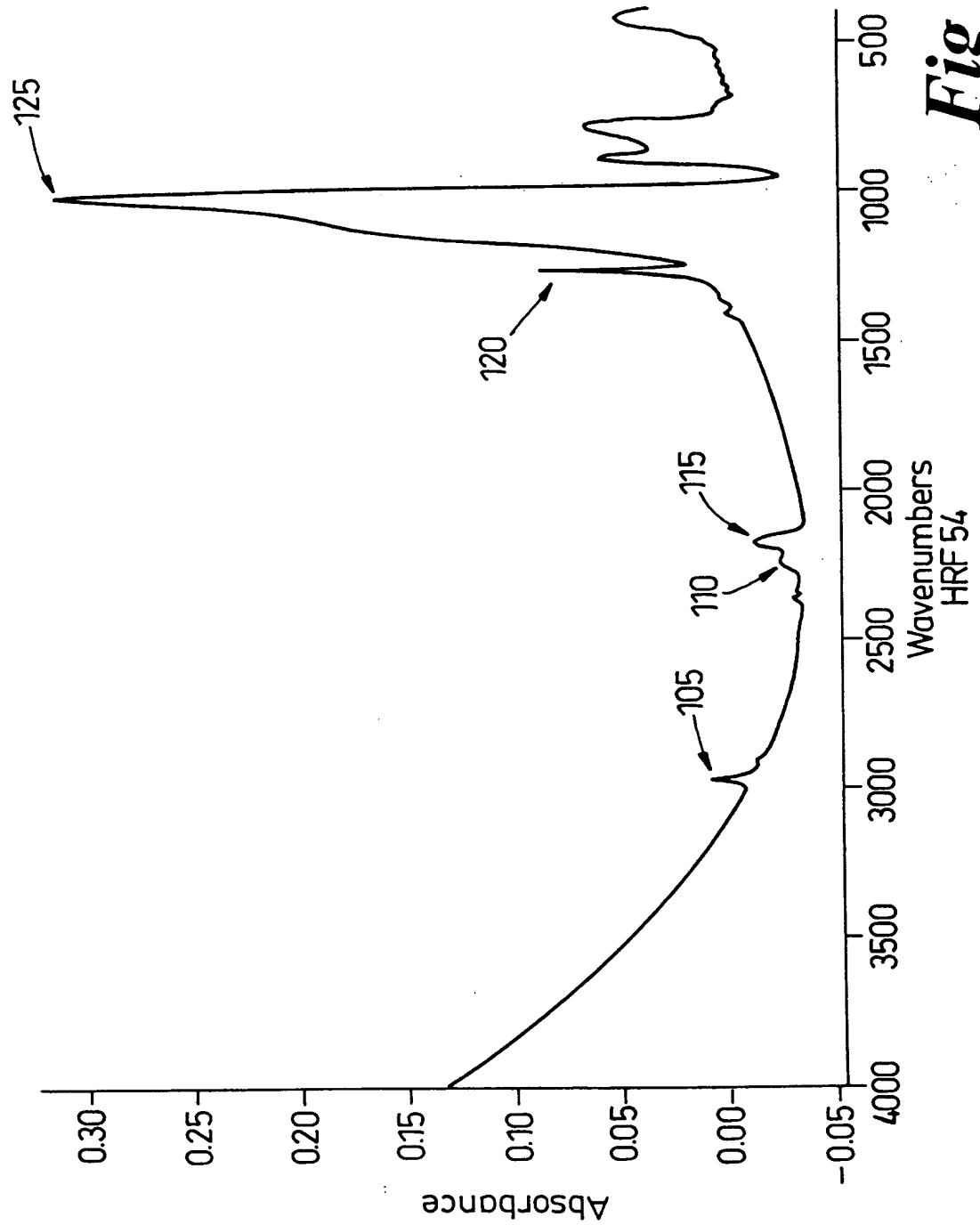


Fig 2



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attney. Doc. No. WLJ.068D
Inventor: John MACNEIL

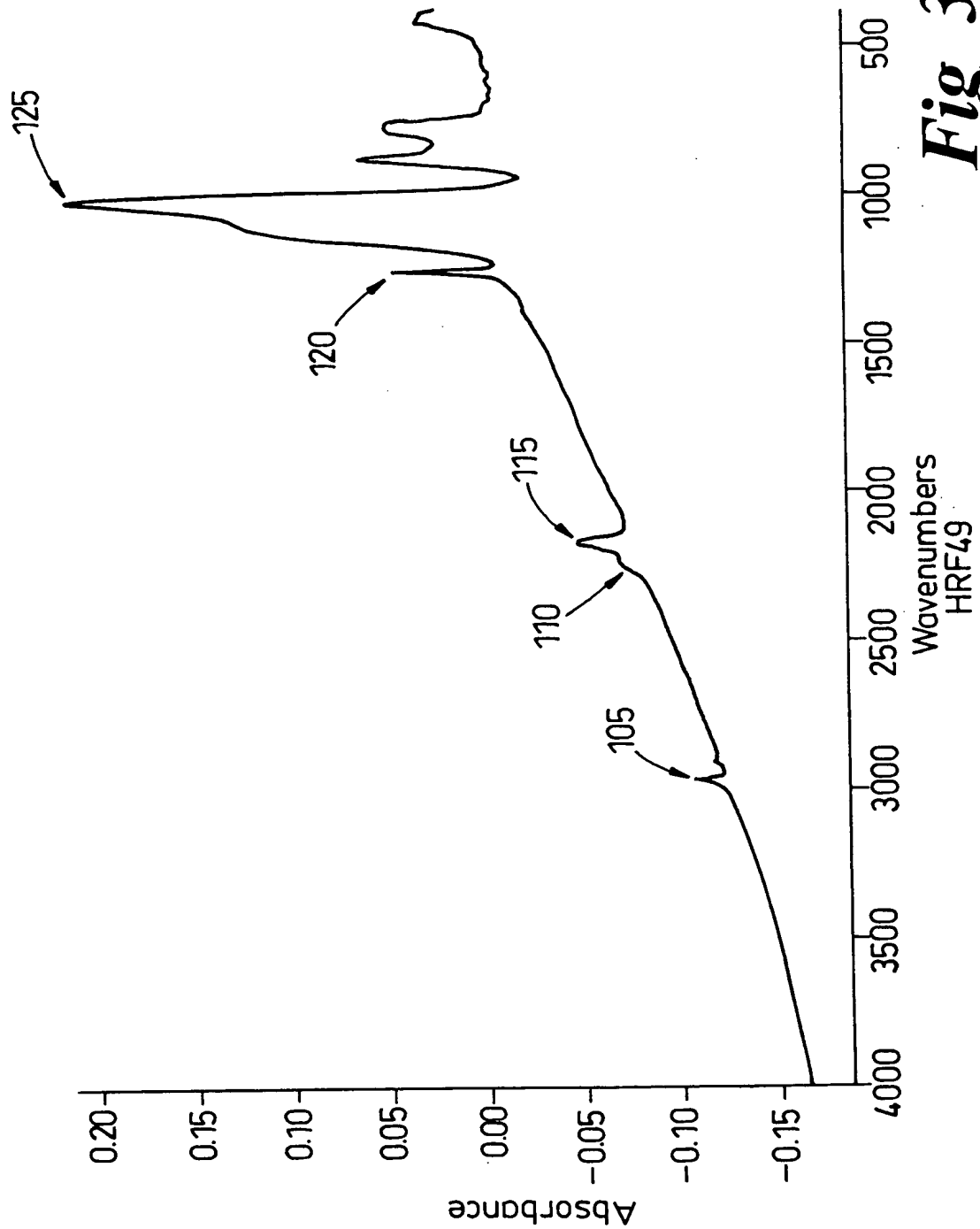
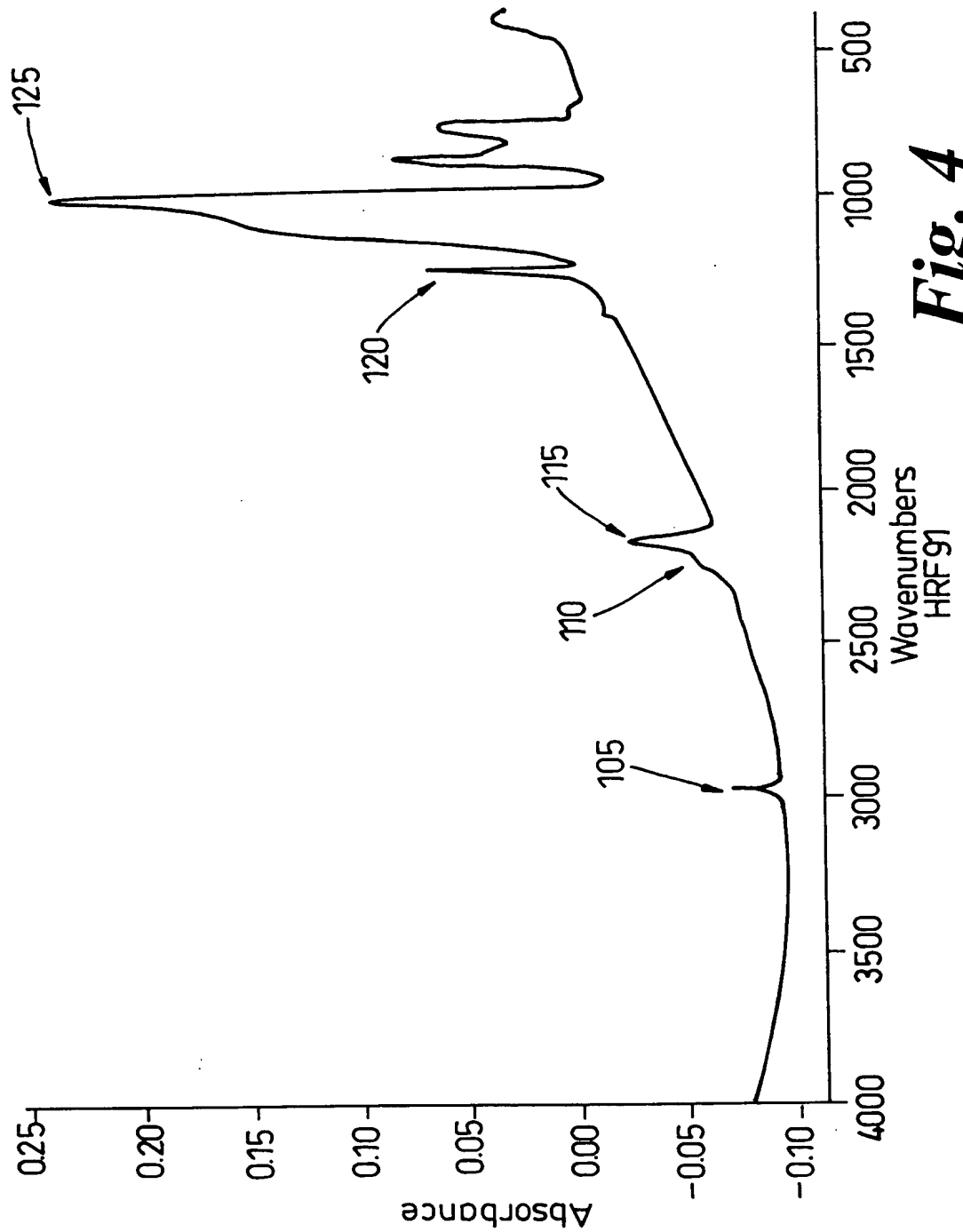


Fig 3



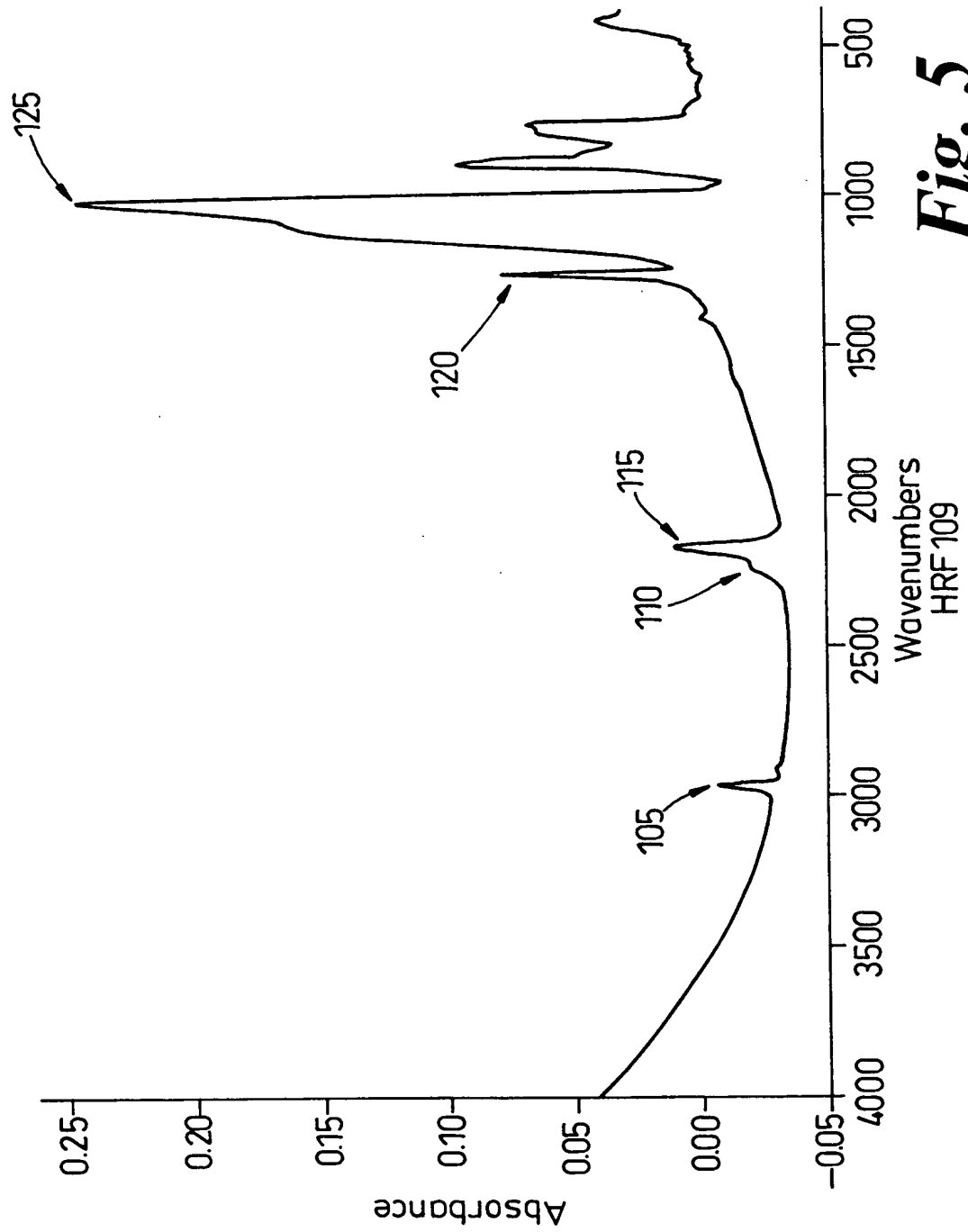


Fig. 5

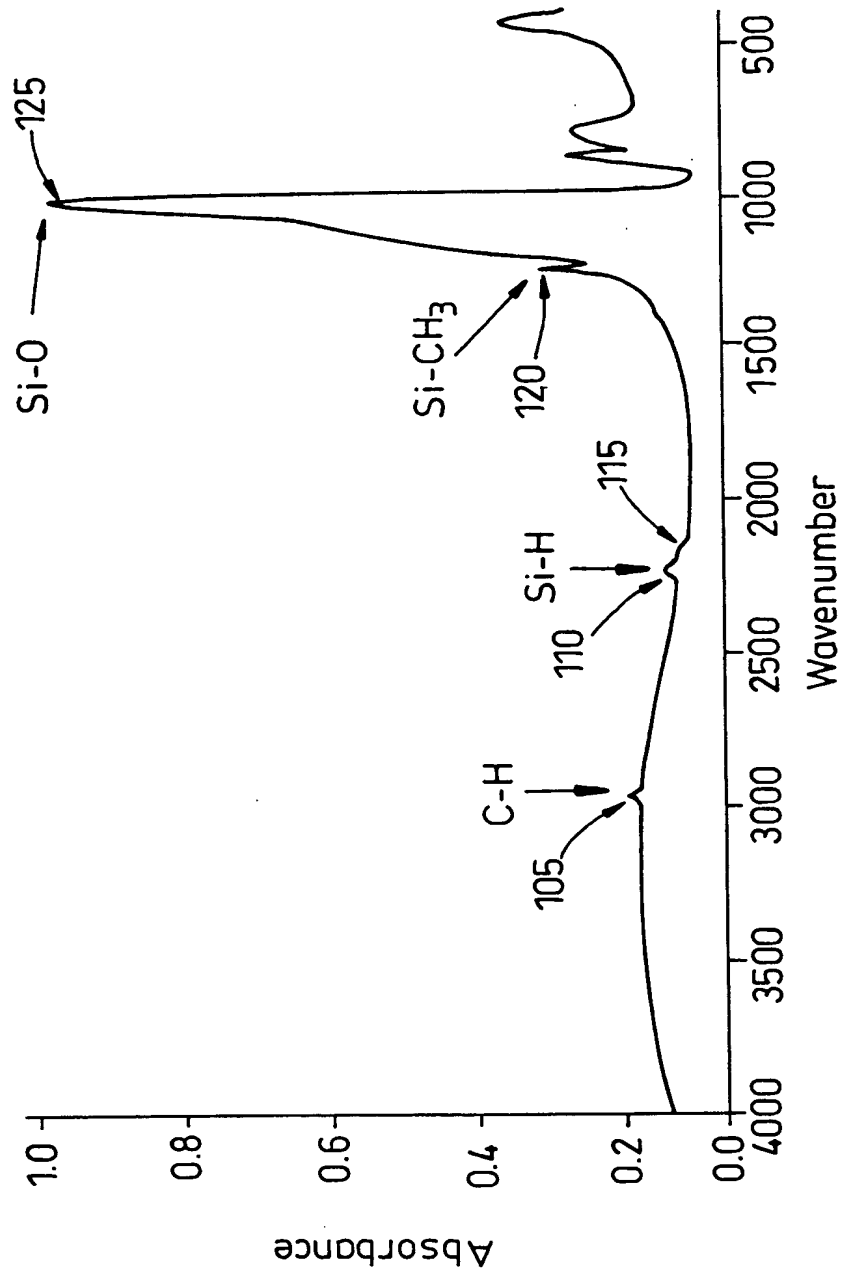


Fig. 6

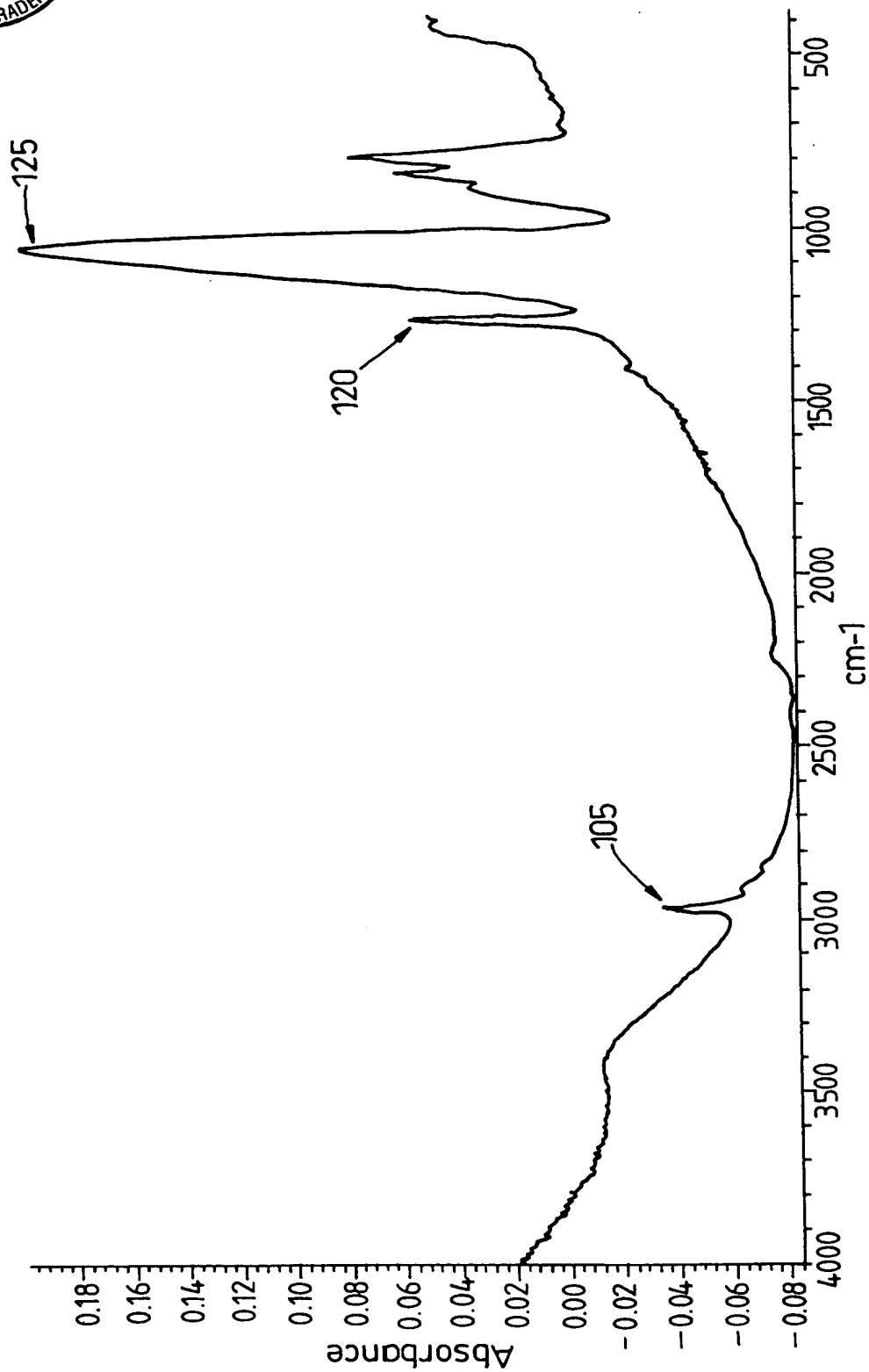


Fig. 7

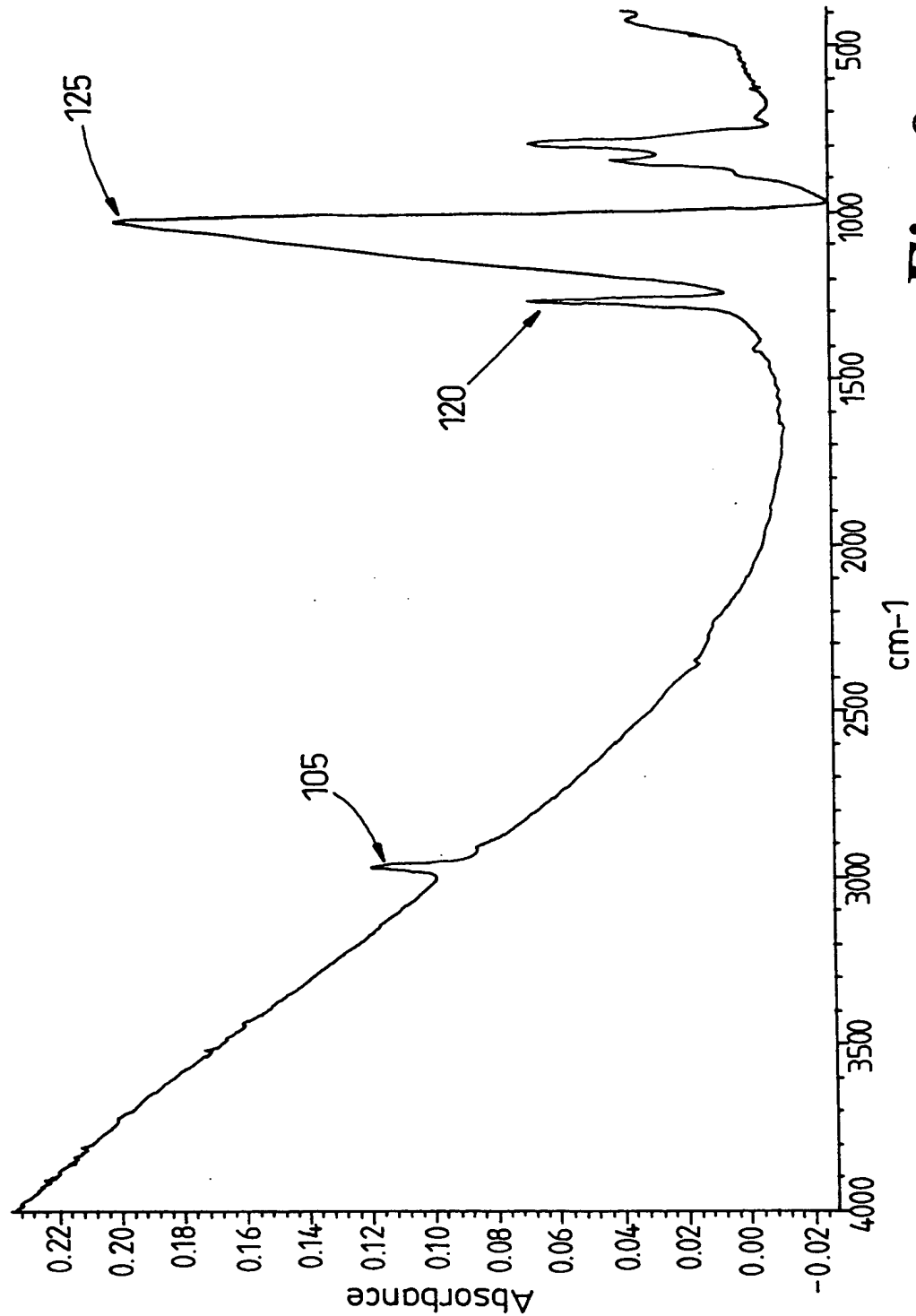


Fig. 8

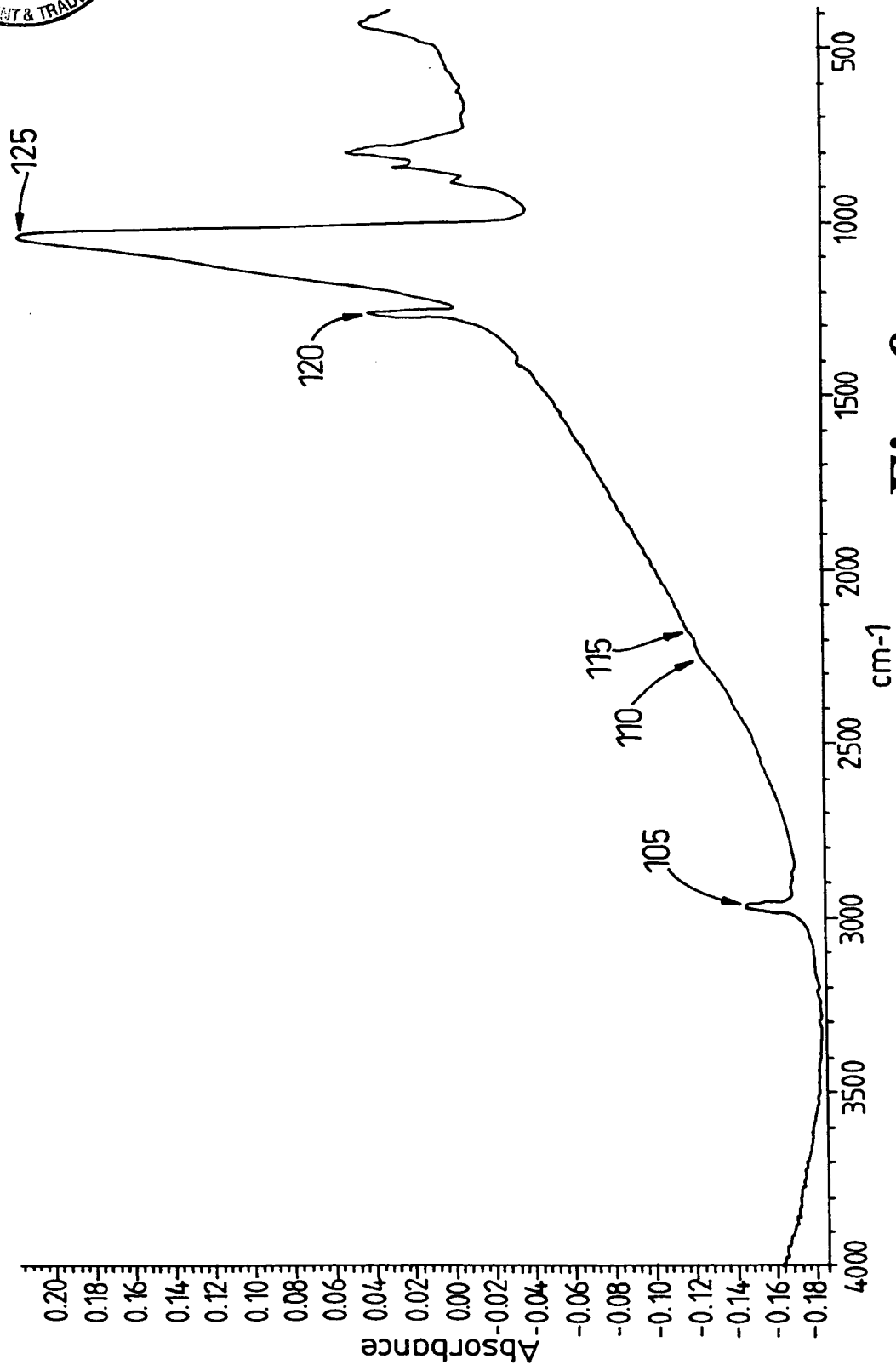


Fig. 9

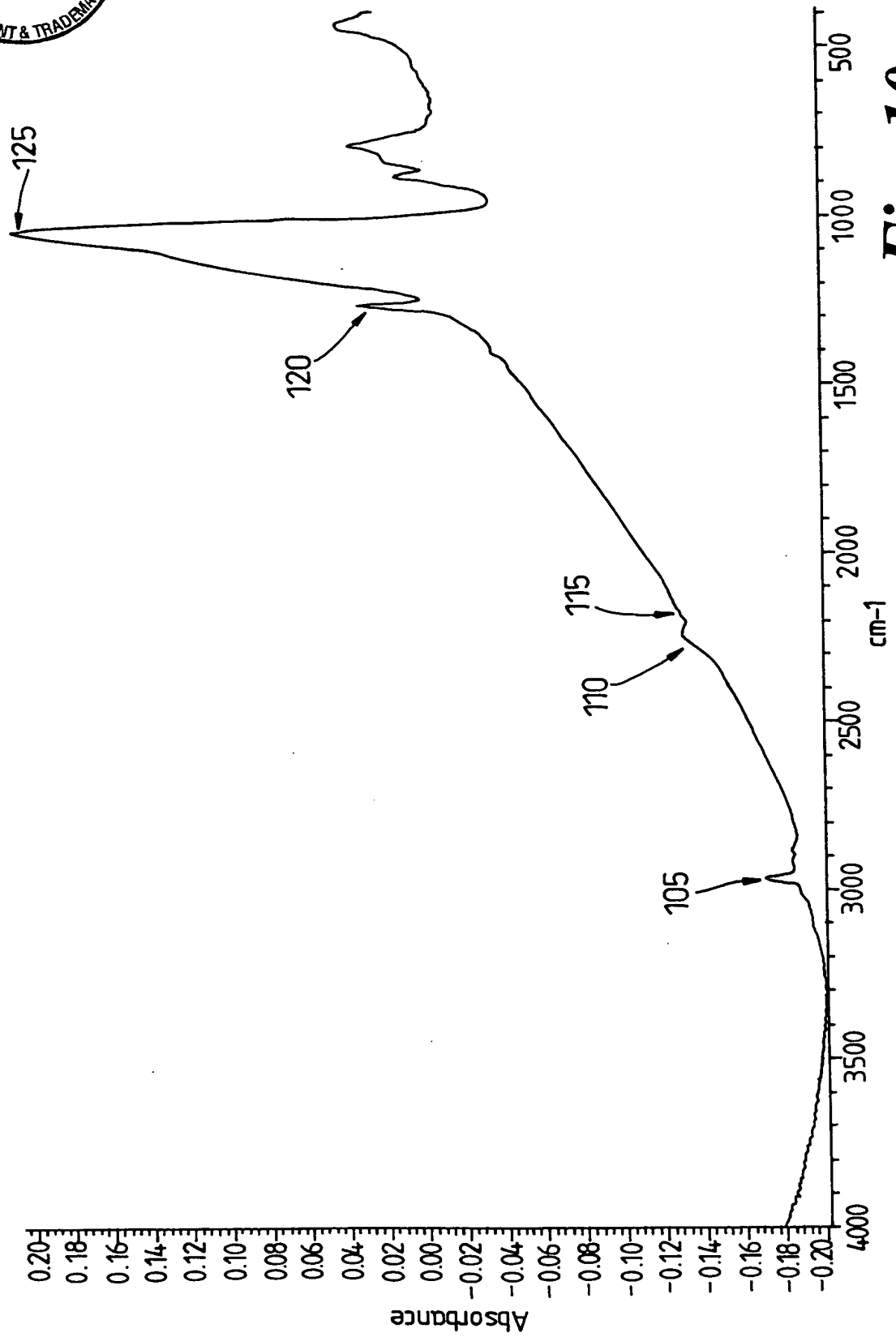


Fig. 10

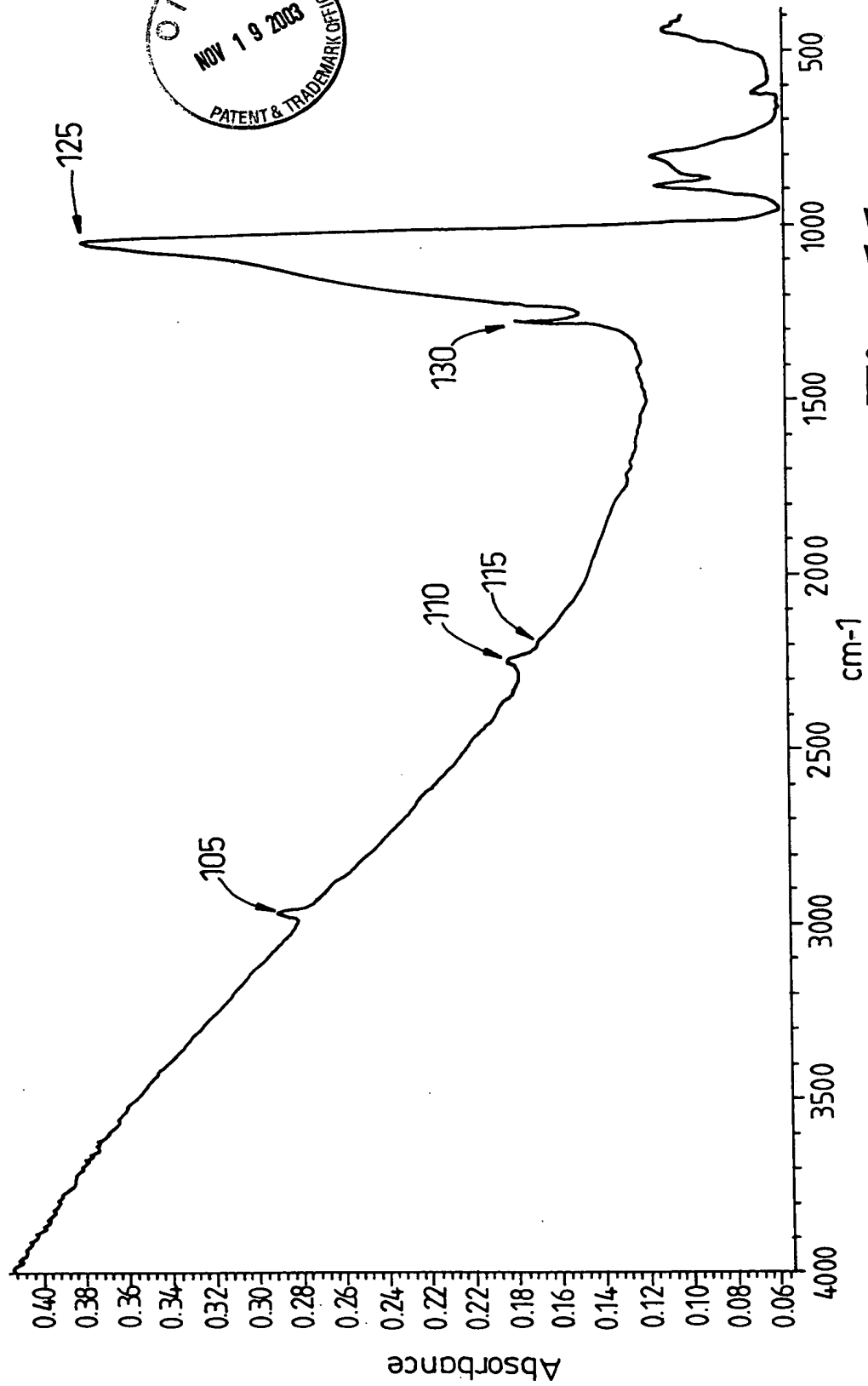


Fig. 11

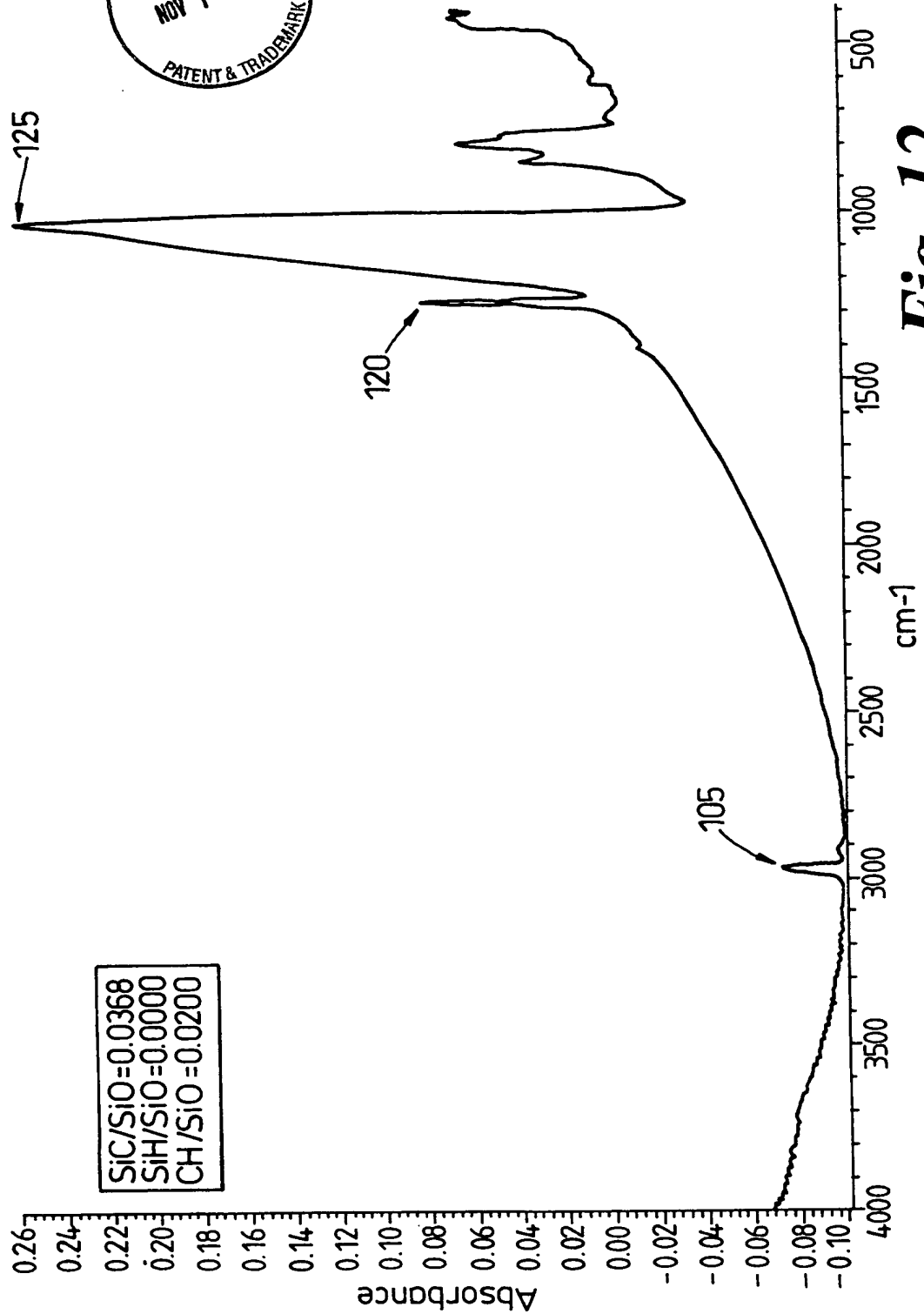


Fig 12

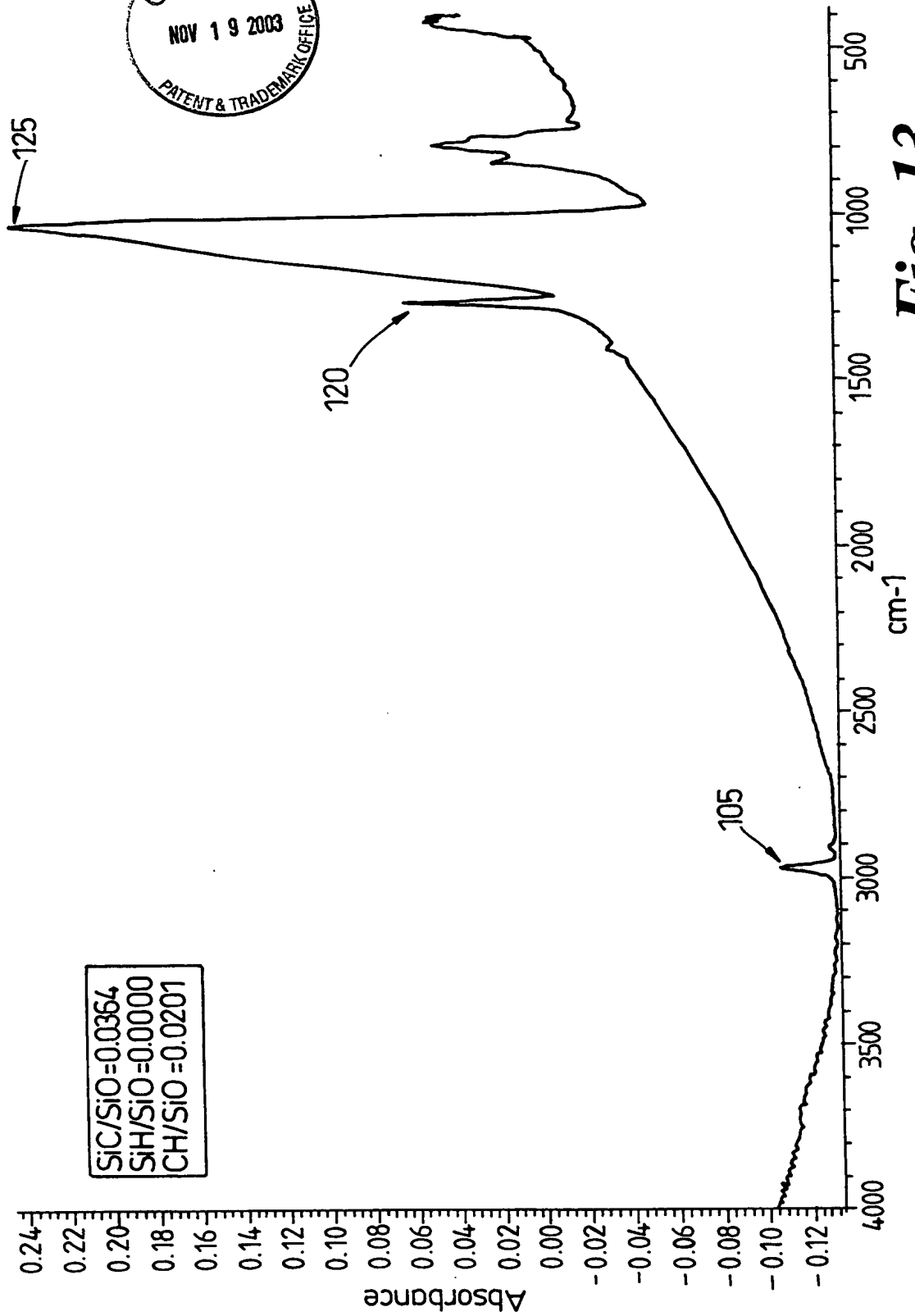


Fig 13

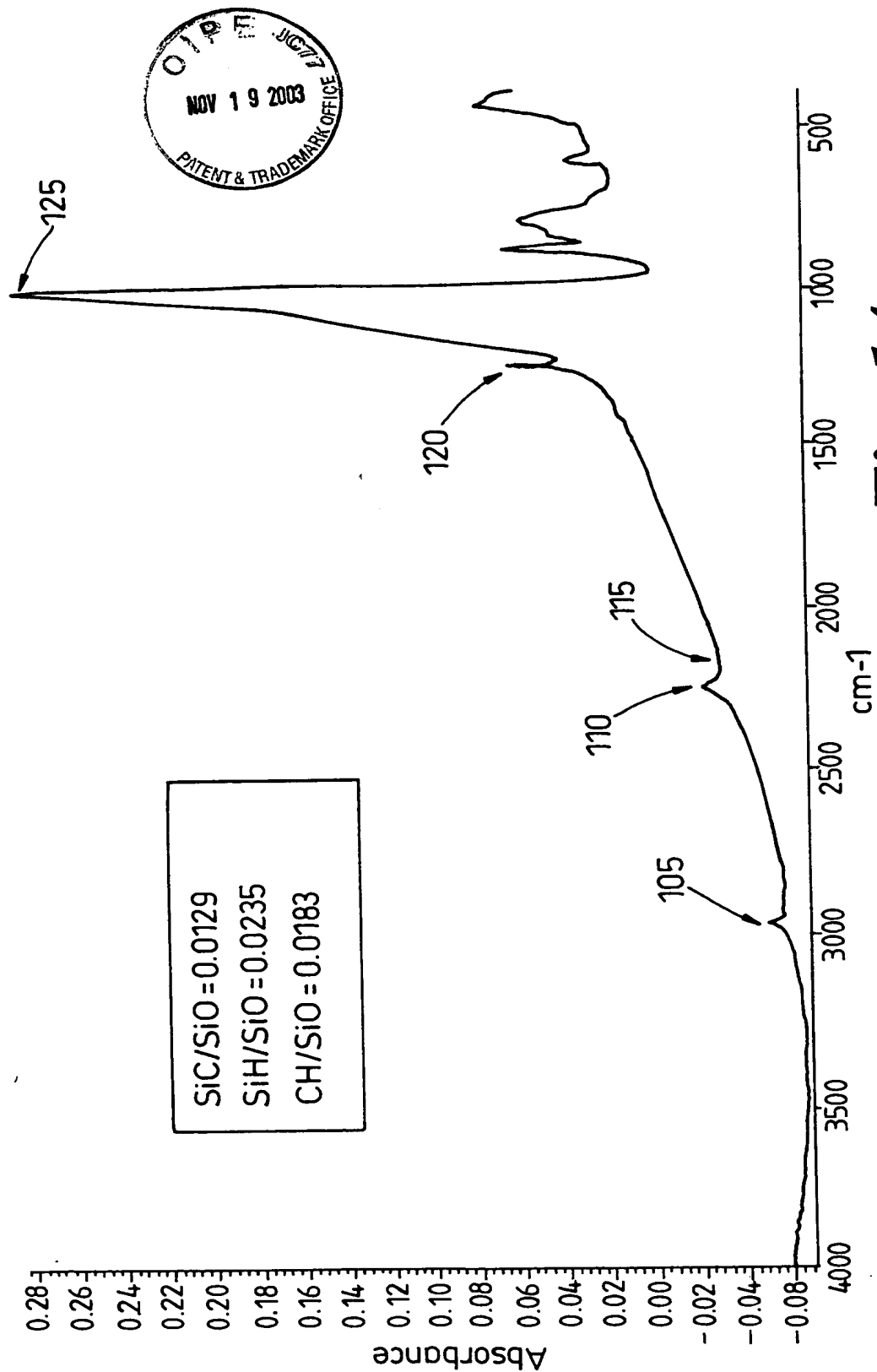


Fig 14

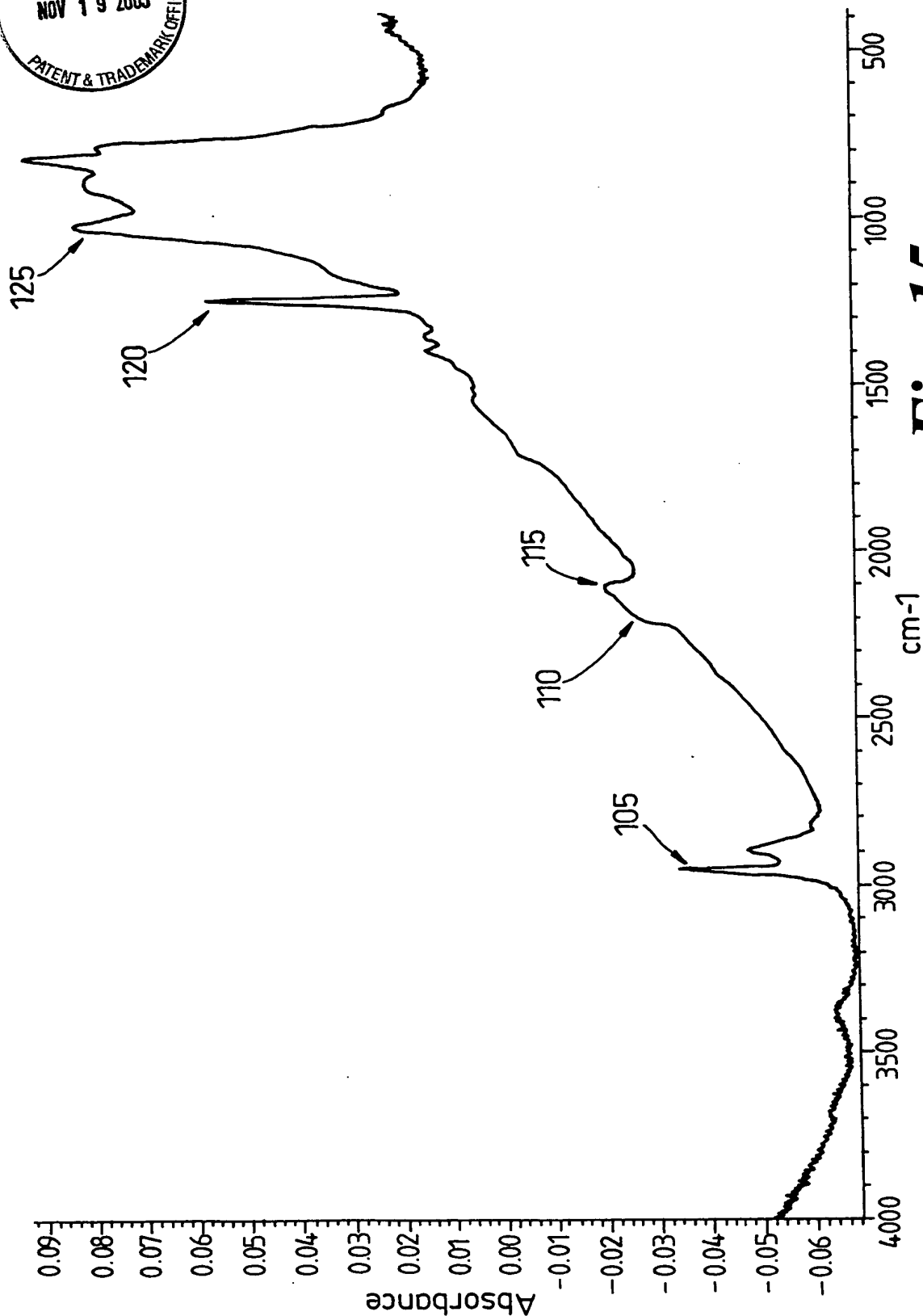


Fig. 15

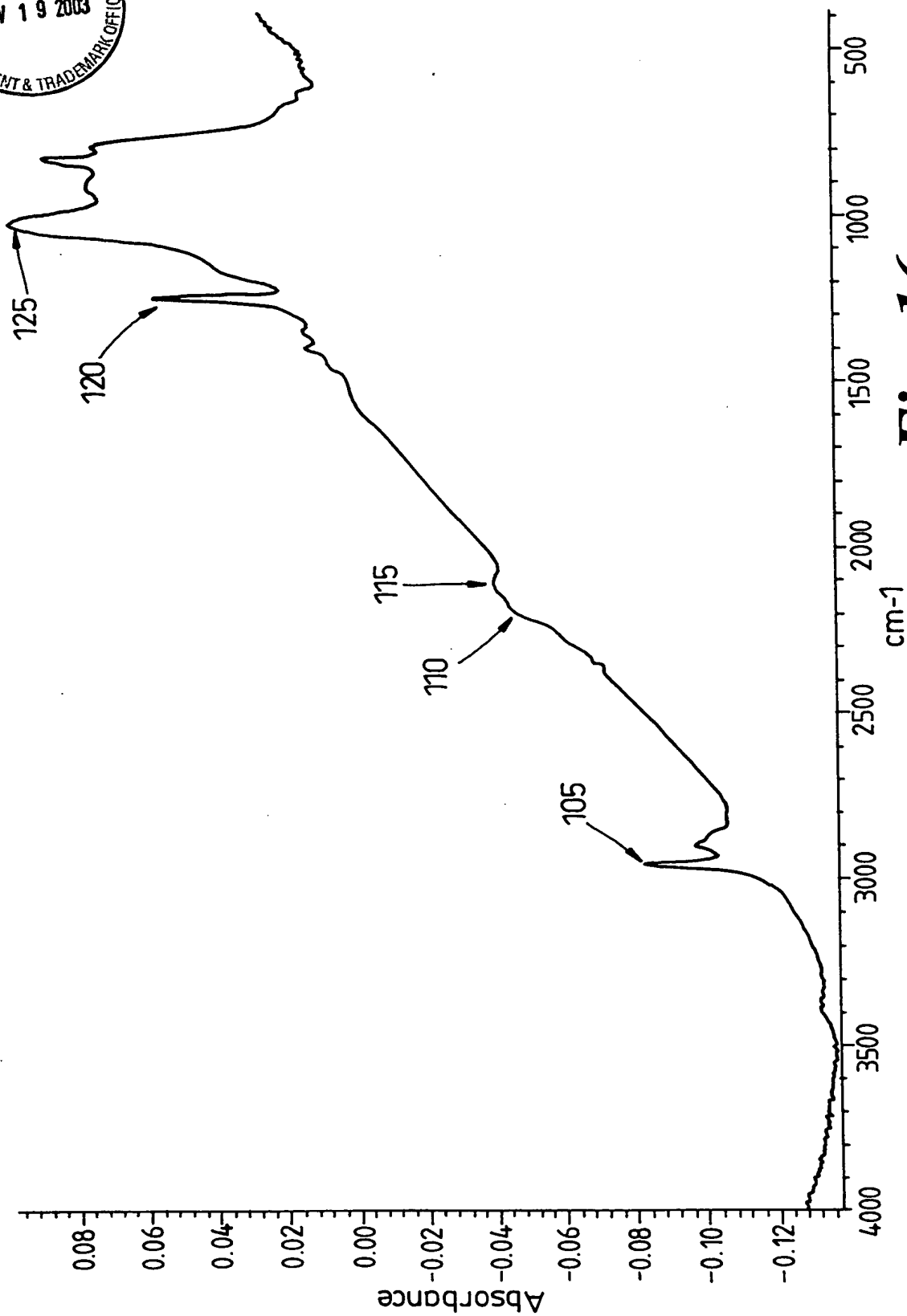


Fig. 16

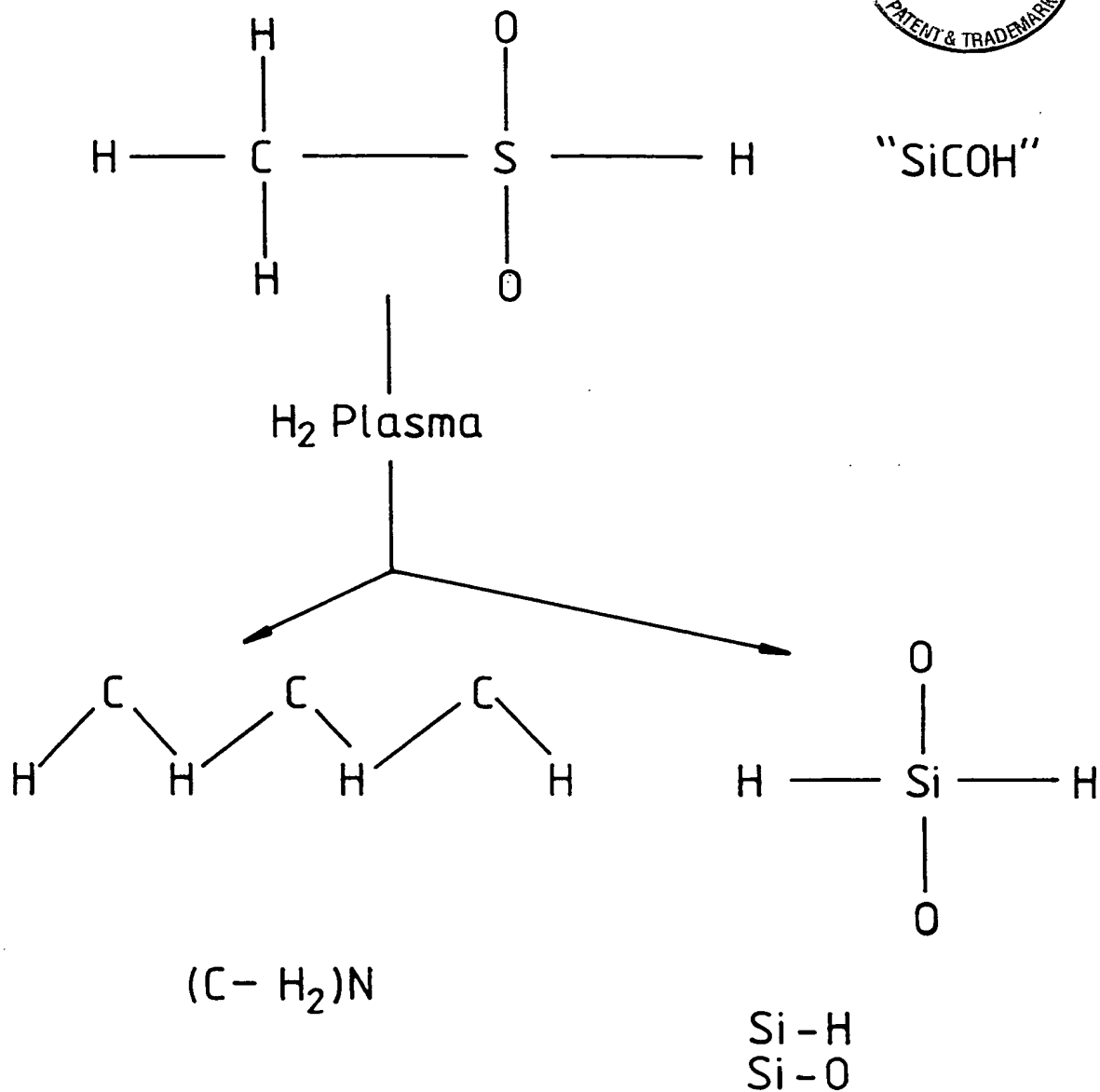


Fig. 17